# **Vishay Semiconductors**

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Hyperfast Rectifier, 60 A FRED Pt<sup>®</sup> G5



### LINKS TO ADDITIONAL RESOURCES



PRIMARY CHARACTERISTICS					
I <sub>F(AV)</sub>	60 A				
V <sub>R</sub>	600 V				
V <sub>F</sub> at I <sub>F</sub> at 125 °C	1.4 V				
t <sub>rr</sub> (typ.)	26				
I <sub>FSM</sub>	480				
T <sub>J</sub> max.	175 °C				
Package	TO-247AD 3L				
Circuit configuration	Single				

### FEATURES

- Hyperfast and optimized Q<sub>rr</sub>
- Best in class forward voltage drop and switching losses trade off
- Optimized for high speed operation
- 175 °C maximum operating junction temperature FREE
- · Polyimide passivation
- Material categorization: for definitions of compliance please see <a href="http://www.vishay.com/doc?99912">www.vishay.com/doc?99912</a>

### **DESCRIPTION / APPLICATIONS**

Featuring a unique combination of low conduction and switching losses, this rectifier is the right choice for soft switched and resonant converters, as well as medium frequency hard switching converters. This device is specifically designed to improve efficiency of high speed LLC output rectification stages of EV / HEV battery charging stations and high frequency stages of UPS applications.

### **MECHANICAL DATA**

Case: TO-247AD 3L Molding compound meets UL 94 V-0 flammability rating Terminal: matte tin plated leads, solderable per J-STD-002

ABSOLUTE MAXIMUM RATINGS							
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Repetitive peak reverse voltage	V <sub>RRM</sub>		600	V			
Average rectified forward current	I <sub>F(AV)</sub>	T <sub>C</sub> = 96 °C, D = 0.50	60				
Non-repetitive peak surge current	I <sub>FSM</sub>	$T_{C}$ = 25 °C, $t_{p}$ = 10 ms, sine wave both anodes, (1) and (3) connected	480	А			
Repetitive peak forward current	I <sub>FRM</sub>	$T_{C} = 96 \ ^{\circ}C, D = 0.50, f = 20 \ \text{kHz}$	120				
Operating junction and storage temperature	T <sub>J</sub> , T <sub>Stg</sub>		-55 to +175	°C			

<b>ELECTRICAL SPECIFICATIONS</b> ( $T_J$ = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS	
Breakdown voltage, blocking voltage	$V_{BR}, V_{R}$	I <sub>R</sub> = 100 μA	600	-	-		
Forward voltage	VF	I <sub>F</sub> = 60 A	-	1.7	2.2	V	
Forward voltage	۷F	I <sub>F</sub> = 60 A, T <sub>J</sub> = 125 °C	-	1.4	-		
Poverse leakage aurrent	1	V <sub>R</sub> = V <sub>R</sub> rated	-	-	25		
Reverse leakage current	I <sub>R</sub>	$T_J = 125 \text{ °C}, V_R = V_R \text{ rated}$	-	-	500	μA	
Junction capacitance	CT	V <sub>R</sub> = 200 V	-	65	-	pF	
Series inductance	L <sub>S</sub>	Measured to lead 5 mm from package body	-	8	-	nH	

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COMPLIANT

HALOGEN

VS-A5PX6006L-N3



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<b>DYNAMIC RECOVERY CHARACTERISTICS</b> (T <sub>J</sub> = 25 °C unless otherwise specified)									
PARAMETER	SYMBOL	TEST CO	MIN.	TYP.	MAX.	UNITS			
		$I_F = 1.0 \text{ A}, \text{ d}I_F/\text{d}t = 100$	) A/µs, V <sub>R</sub> = 30 V	-	26	-			
Reverse recovery time	t <sub>rr</sub>	T <sub>J</sub> = 25 °C		-	44	-	ns		
		T <sub>J</sub> = 125 °C		-	62	-			
Peak recovery current	I <sub>RRM</sub>	T <sub>J</sub> = 25 °C	I <sub>F</sub> = 40 A dI <sub>F</sub> /dt = 1000 A/μs V <sub>R</sub> = 400 V	-	16	-	A		
Feak recovery current		T <sub>J</sub> = 125 °C		-	33	-			
	0	T <sub>J</sub> = 25 °C		-	381	-	nC		
Reverse recovery charge	Q <sub>rr</sub>	T <sub>J</sub> = 125 °C		-	1283	-			
Boyoroo roooyony timo	+	T <sub>J</sub> = 25 °C	I <sub>F</sub> = 60 A dI <sub>F</sub> /dt = 1000 A/μs V <sub>R</sub> = 400 V	-	46	-	20		
Reverse recovery time	t <sub>rr</sub>	T <sub>J</sub> = 125 °C		-	67	-	ns		
Deels receiver a current	I <sub>RRM</sub>	T <sub>J</sub> = 25 °C		-	17	-	А		
Peak recovery current		T <sub>J</sub> = 125 °C		-	37	-	A		
	•	T <sub>J</sub> = 25 °C		-	462	-			
Reverse recovery charge	Q <sub>rr</sub>	T <sub>J</sub> = 125 °C		-	1568	-	nC		

THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS		
Thermal resistance, junction-to-case	R <sub>thJC</sub>		-	-	0.63	°C/W		
Weight			-	5.5	-	g		
Weight			-	0.2	-	oz.		
Mounting torque			6 (5)	-	12 (10)	kgf · cm (lbf · in)		
Maximum junction and storage temperature range	T <sub>J</sub> , T <sub>Stg</sub>		-55	-	175	°C		
Marking device		Case style: TO-247AD 3L	A5PX6006L					

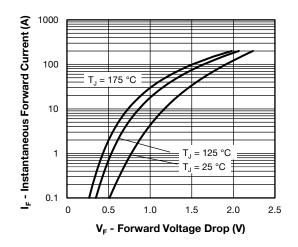


Fig. 1 - Forward Voltage Drop Characteristics

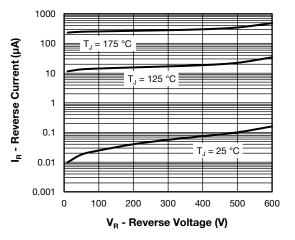
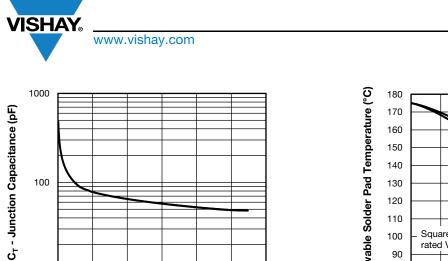


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage



# 140 130 120 110 100

600

100 200 300 400 500 V<sub>R</sub> - Reverse Voltage (V)

100

10

0

Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

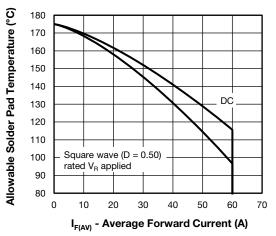


Fig. 4 - Maximum Allowable Case Temperature vs. Average Forward Current

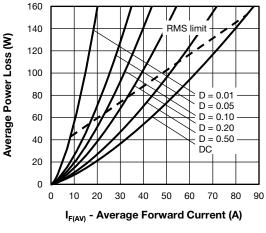


Fig. 5 - Forward Power Loss Characteristics

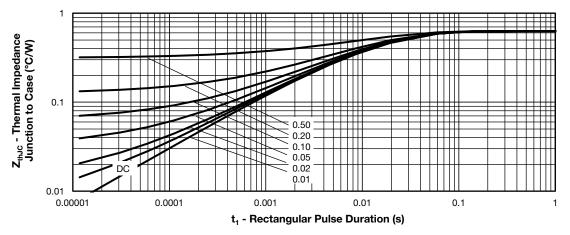


Fig. 6 - Transient Thermal Impedance, Junction to Case

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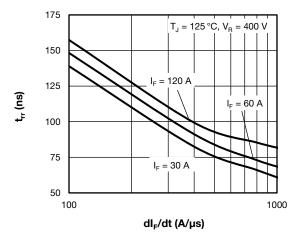


Fig. 7 - Typical Reverse Recovery Time vs. dl<sub>F</sub>/dt

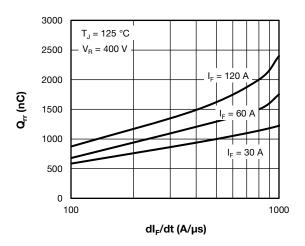


Fig. 8 - Typical Reverse Recovery Charge vs. dl<sub>F</sub>/dt

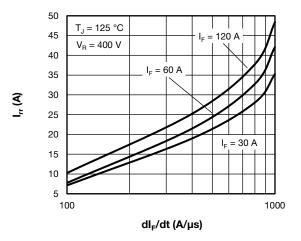
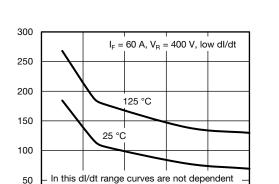


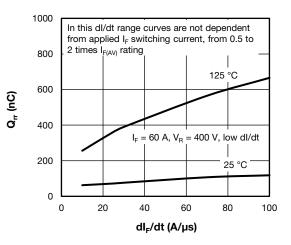
Fig. 9 - Typical Reverse Recovery Current vs. dl<sub>F</sub>/dt



t<sub>rr</sub> (ns)

50 L In this dl/dt range curves are not dependent from applied I<sub>F</sub> switching current, from 0.5 to 2 times I<sub>F(AV)</sub> rating 0 20 40 60 80 100 dl<sub>F</sub>/dt (A/µs)

Fig. 10 - Typical Reverse Recovery Time vs. dl<sub>F</sub>/dt





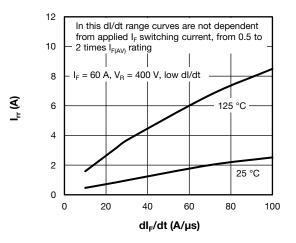


Fig. 12 - Typical Reverse Recovery Current vs. dl<sub>F</sub>/dt

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VS-A5PX6006L-N3

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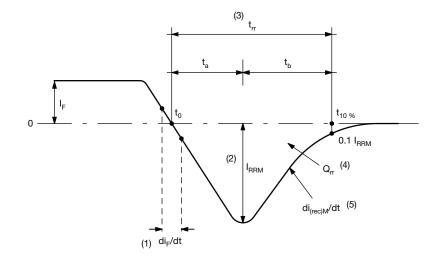


Fig. 13 - Reverse Recovery Waveform and Definitions

### Notes

- <sup>(1)</sup> di<sub>F</sub>/dt rate of change of current through zero crossing
- $^{(2)}\ \ I_{RRM}$  peak reverse recovery current
- $^{(3)}$  t<sub>rr</sub> reverse recovery time measured from t<sub>0</sub>, crossing point of negative going I<sub>F</sub>, to point t<sub>10%</sub>, 0.1 I<sub>RRM</sub>
- $^{(4)}~~Q_{rr}$  area under curve defined by  $t_0$  and  $t_{10~\%}$

$$Q_{rr} = \int_{t_0}^{t_{10}\%} I(t)dt$$

 $^{(5)}$  di<sub>(rec)</sub>M/dt - peak rate of change of current during t<sub>b</sub> portion of t<sub>rr</sub>

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### **ORDERING INFORMATION TABLE**

Device code	VS-	Α	5	Ρ	x	60	06	L	-N3
	1	2	3	4	5	6	7	8	9
	1       -         2       -         3       -         4       -         5       -         6       -         7       -         8       -         9       -	Circ A = 5 = Pac P = X = Cur Volt Pac	nay Serr suit confi single o Fred ge kage: TO-247 hyperfa rent ratil age ratil kage: L ironmer = halog	iguratior diode, 2 neratior packag st recov ng (60 = ng (06 = = long l atal digit	anodes o 5 eery 60 A) 600 V) ead (TC	)-247A[	,	totally I	ead (Pb

ORDERING INFORMATION (Example)						
PREFERRED P/N QUANTITY PER TUBE MINIMUM ORDER QUANTITY PACKAGING DESCRIPTION						
VS-A5PX6006L-N3	25	500	Antistatic plastic tube			

LINKS TO RELATED DOCUMENTS					
Dimensions	www.vishay.com/doc?95626				
Part marking information	www.vishay.com/doc?95007				
SPICE model	www.vishay.com/doc?96958				



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TO-247AD 3L

### **DIMENSIONS** in millimeters and inches



View B

SYMBOL	MILLIN	IETERS	INCHES		NOTES
STIVIBOL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.65	5.31	0.183	0.209	
A1	2.21	2.59	0.087	0.102	
A2	1.50	2.49	0.059	0.098	
b	0.99	1.40	0.039	0.055	
b1	0.99	1.35	0.039	0.053	
b2	1.65	2.39	0.065	0.094	
b3	1.65	2.34	0.065	0.092	
b4	2.59	3.43	0.102	0.135	
b5	2.59	3.38	0.102	0.133	
с	0.38	0.89	0.015	0.035	
c1	0.38	0.84	0.015	0.033	
D	19.71	20.70	0.776	0.815	3
D1	13.08	-	0.515	-	4

(2, 52, 51) (4) Section C - C, D - D, E - E

SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STNIBOL	MIN.	MAX.	MIN.	MAX.	NOTES
D2	0.51	1.30	0.020	0.051	
E	15.29	15.87	0.602	0.625	3
E1	13.46	-	0.53	-	
е	5.46	BSC	0.215	5 BSC	
ØК	0.2	0.254		0.010	
L	19.81	20.32	0.780	0.800	
L1	3.71	4.29	0.146	0.169	
ØР	3.56	3.66	0.14	0.144	
Ø P1	-	6.98	-	0.275	
Q	5.31	5.69	0.209	0.224	
R	4.52	5.49	0.178	0.216	
S	5.51 BSC		0.217	' BSC	

#### Notes

- <sup>(1)</sup> Dimensioning and tolerancing per ASME Y14.5M-1994
- (2) Contour of slot optional
- <sup>(3)</sup> Dimension D and E do not include mold flash. These dimensions are measured at the outermost extremes of the plastic body
- <sup>(4)</sup> Thermal pad contour optional with dimensions D1 and E1
- <sup>(5)</sup> Lead finish uncontrolled in L1
- (6) Ø P to have a maximum draft angle of 1.5 to the top of the part with a maximum hole diameter of 3.91 mm (0.154")
- <sup>(7)</sup> Outline conforms to JEDEC<sup>®</sup> outline TO-247 with exception of dimension A min., D, E min., Q min., S, and note 4

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